

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Divisional Patent Application of)
Ritsuko KAWASAKI et al.)
Based On Application No. 10/124,489) Attn: Applications
Which Was Filed: April 18, 2002) Branch
For: METHOD FOR MANUFACTURING A)
SEMICONDUCTOR DEVICE) Date: August 27, 2003

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P.O. Box 1450
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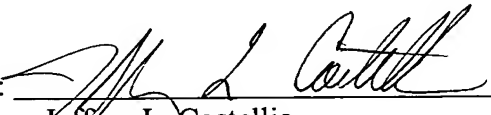
Sir:

In accordance with the duty of disclosure as set forth in 37 C.F.R. §1.56, Applicants hereby submit the following information in conformance with 37 C.F.R. §§ 1.97 and 1.98.

The references listed on the attached Form PTO-1449 were cited in parent application Serial No. 10/124,489 filed April 18, 2002, and its predecessor Application No. 09/612,100, from which priority is claimed under 35 U.S.C. 120.

It is requested that the accompanying PTO-1449 be considered and made of record in the above-identified application. To assist the Examiner, the documents are listed on the attached form PTO-1449. It is respectfully requested that an Examiner initialed copy of this form be returned to the undersigned.

Respectfully submitted,

By: 
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PTO/SB/08A (08-00)

Approved for use through 10/31/2002. OMB 0651-0031

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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Complete if Known	
				Application Number	New Application
				Filing Date	August 27, 2003
				First Named Inventor	Ritsuko KAWASAKI et al.
				Group Art Unit	2818
				Examiner Name	Q. Hoang
				Attorney Docket Number	740756-2645
Sheet	1	of	1		

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cited No.	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
		US-5,612,251		Lee	03/18/1997	
		US-5,767,003		Noguchi	06/16/1998	
		US-6,020,224		Shimogaichi et al	02/21/2000	
		US-6,246,524		Tanaka	06/12/2001	
		US-6,248,606		Ino et al	06/19/2001	
		US-5,953,597		Kusumoto et al	09/14/1999	
		US-5,643,826		Ohtani et al	07/01/1997	
		US-5,923,962		Ohtani et al	07/13/1999	
		US-6,426,245 B1		Kawasaki et al.	07/30/2002	
		US-6,380,009		Battersby	04/2002	

FOREIGN PATENT DOCUMENTS							
Examiner Initials ¹	Cited No.	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Office ³	Number ⁴	Kind Code ⁵ (if known)			
		JP	08-228006 A			09/03/1996	Abstract
		JP	07-130652 A			05/19/1995	Abstract

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials ¹	Cited No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
		K. Shimizu, O. Sugiura, M. Matsumura, "High Mobility Poly-Si Thin Film Transistors Fabricated by a Novel Excimer Laser Crystallization Method", IEEE Transactions on Electron Devices, Vol., 40, No. 1, pp. 112-117, January, 1993.	

Examiner Signature		Date Considered	
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

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